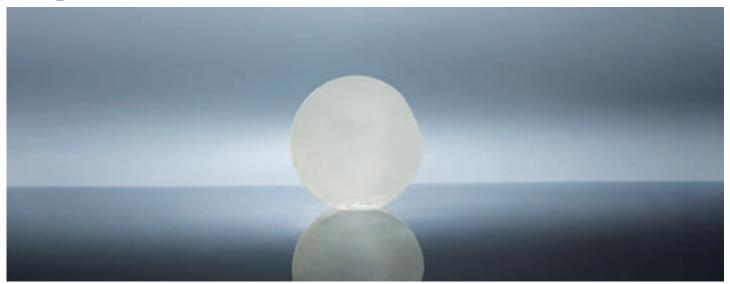


MgO:LiNbO3



DESCRIPTION

MgO:LiNbO₃ crystals, also known as magnesium-doped lithium niobate crystals, are electro-optic crystals with excellent overall properties. MgO-doped LN (typical doping: 5%) was developed to reduce the optical folding effect of the intrinsic material and thus can be used for higher energy applications. MgO:LiNbO₃ has special advantages for NCPM SHG, hybrid SFG, and optical parametric oscillators of Nd:Laser and thus has applications in OPO, OPA, quasi-phase-matching multipliers, and integrated waveguides. MgO:LiNbO₃ crystals have unique advantages over LiNbO₃ crystals for NCPM multiplication, mixing, and optical parametric oscillation in Nd-doped lasers, where MgO:LiNbO₃ crystals can achieve multiplication efficiencies over 65% for pulsed Nd:YAG lasers and 45% for continuous Nd:YAG lasers. crystals are widely used in optical parametric oscillation (OPO), optical parametric amplification (OPA), quasi-phase matching, and integrated optical waveguides.

FEATURES

- High damage threshold
- Wide range of transparency
- Excellent EO and NLO performance
- Good mechanical and chemical properties
- Non-critical phase matching at room temperature

APPLICATIONS

- SHG
- Waveguide modulator
- Electro-optical modulator
- Rangefinder LIDAR cell phone
- For 1064nm laser room temperature doubling
- Q-switched:YAG lasers as Nd

CRYSTAL SPECIFICATION

Crystal Materials	MgO:LiNbO ₃
Size	Customized
Dimensional Tolerance	±0.1mm
Length Tolerance	±0.2mm
Surface quality	20/10 S/D
Parallelism	<20 arc seconds
Flatness	<λ/10 @633nm
Perpendicularity	<5 arc minutes
Chamfering	0.2mm @45°
Directional Tolerance	<10 arc minutes
Wavefront distortion	<λ/4 @633nm



MgO:LiNbO3

CRYSTAL CHARACTERISTICS

Melting point	1255±5℃
Curie Point	1140±5℃
Mohs Hardness	5
Density	4.64g/cm ³
Absorption coefficient	~ 0.1%/cm@1064nm
Solubility	Insoluble in water
Relative dielectric constant	e ^T ₁₁ /e ₀ :85
	e ^T ₃₃ /e ₀ :29.5
Thermal conductivity	38W/m/k@25℃
Transparency range	420-5000nm
Refractive index	n _e =2.146,n _o =2.220@1300nm
	n _e =2.156,n _o =2.322@1064nm
	n _e =2.203,n _o =2.286@632.8nm
Optical uniformity	~5 ×10 ⁻⁵ /cm
Sellmeier equation	$n_0^2(\lambda) = 4.9048 + 0.11768/(\lambda^2 - 0.04750) - 0.027169\lambda^2$
	$n_e^2(\lambda) = 4.5820 + 0.099169/(\lambda^2 - 0.04443) - 0.021950\lambda^2$
Electro-optical coefficient	Y ^T ₃₃ =32pm/V,Y ^s ₃₃ =31pm/V
	$Y^{T}_{31}=10 \text{pm/V}, Y^{S}_{31}=8.6 \text{pm/V}$
	Y ^T ₂₂ =6.8pm/V,Y ^S ₂₂ =3.4pm/V
Half-wave voltage (DC)	3.03KV
Damage Threshold	200MW/cm ² (10ns)

SPECTRA

